# Diodes, Dual 40 Watt Peak Power, High Temperature

SC-70 Dual Common Anode Zeners

## MMBZHxxVAWT1G Series, SZMMBZHxxVAWT1G Series

These dual monolithic silicon Zener diodes are designed for applications requiring transient overvoltage ESD protection capability. They are intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment and other applications. Their dual junction common anode design protects two separate lines using only one package. These devices are high temperature rated and ideal for use in high reliability applications where board space is at a premium.

#### Features

- SC-70 Package Allows Either Two Separate Unidirectional Configurations or a Single Bidirectional Configuration
- Standard Zener Breakdown Voltage Range: 12 33 V
- Peak Power 40 W @ 1.0 ms (Unidirectional), per Figure 5 Waveform
- ESD Rating:
  - Class 3B (> 16 kV) per the Human Body Model
    Class C (> 400 V) per the Machine Model
- Low Leakage < 5.0 μA
- Flammability Rating UL 94 V-0
- 175°C T<sub>J(MAX)</sub> Rated for High Temperature, Mission Critical Applications
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These are Pb–Free Devices\*

#### Mechanical Characteristics:

**CASE:** Void-free, transfer-molded, thermosetting plastic case **FINISH:** Corrosion resistant finish, easily solderable

MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:

260°C for 10 Seconds

Package designed for optimal automated board assembly Small package size for high density applications Available in 8 mm Tape and Reel

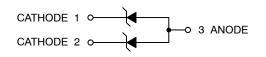
Use the Device Number to order the 7 inch/3,000 unit reel.



#### **ON Semiconductor®**







#### MARKING DIAGRAM



XX = Specific Device Code M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MMBZHxxVAWT1G	SC–70 (Pb–Free)	3,000 / Tape & Reel
SZMMBZHxxVAWT1G	SC–70 (Pb–Free)	3,000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### **DEVICE MARKING INFORMATION**

See specific marking information in the device marking column of the table on page 2 of this data sheet.

#### MMBZHxxVAWT1G Series, SZMMBZHxxVAWT1G Series

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Power Dissipation @ 1.0 ms (Note 1) @ $T_L \le 25^{\circ}C$	P <sub>pk</sub>	40	W
Total Power Dissipation on FR–5 Board (Note 2) @ $T_A = 25^{\circ}C$ Derate above 25°C	PD	225 1.5	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 2)	R <sub>0JA</sub>	605	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	– 55 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Non-repetitive current pulse per Figure 5 and derate above  $T_A = 25^{\circ}C$  per Figure 6.

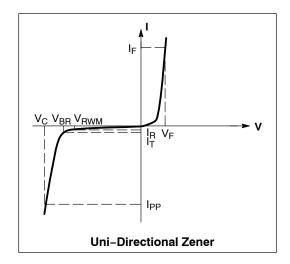
2.  $FR-5 = 1.0 \times 0.75 \times 0.62$  in.

#### **ELECTRICAL CHARACTERISTICS**

#### (T<sub>A</sub> = $25^{\circ}$ C unless otherwise noted)

UNIDIRECTIONAL (Circuit tied to Pins 1 and 3 or 2 and 3)

Symbol	Parameter					
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current					
V <sub>C</sub>	Clamping Voltage @ IPP					
V <sub>RWM</sub>	Working Peak Reverse Voltage					
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>					
V <sub>BR</sub>	Breakdown Voltage @ I <sub>T</sub>					
Ι <sub>Τ</sub>	Test Current					
$\Theta V_{BR}$	Maximum Temperature Coefficient of $V_{BR}$					
١ <sub>F</sub>	Forward Current					
V <sub>F</sub>	Forward Voltage @ I <sub>F</sub>					
Z <sub>ZT</sub>	Maximum Zener Impedance @ I <sub>ZT</sub>					
I <sub>ZK</sub>	Reverse Current					
Z <sub>ZK</sub>	Maximum Zener Impedance @ I <sub>ZK</sub>					



#### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

UNIDIRECTIONAL (Circuit tied to Pins 1 and 3 or Pins 2 and 3)

(V<sub>F</sub> = 0.9 V Max @ I<sub>F</sub> = 10 mA)

			I <sub>R</sub> @	Breakdown Voltage			V <sub>C</sub> @ I <sub>PP</sub> (Note 4)			
	Device	V <sub>RWM</sub>	V <sub>RWM</sub>	VB	R (Note 3)	(V)	@ I <sub>T</sub>	Vc	I <sub>PP</sub>	$\Theta V_{BR}$
Device*	Marking	Volts	nA	Min	Nom	Max	mA	V	Α	mV/°C
MMBZH12VAWT1G	CK	8.5	200	11.40	12	12.60	1.0	17	2.35	7.5
MMBZH15VAWT1G	AJ	12	50	14.25	15	15.75	1.0	21	1.9	12.3
MMBZH20VAWT1G**	-	17	50	19.00	20	21.00	1.0	28	1.4	17.2
MMBZH27VAWT1G**	_	22	50	25.65	27	28.35	1.0	40	1.0	24.3
MMBZH33VAWT1G**	-	26	50	31.35	33	34.65	1.0	46	0.87	30.4

3. V\_BR measured at pulse test current  $I_T$  at an ambient temperature of 25°C.

4. Surge current waveform per Figure 5 and derate per Figure 6.

\*Includes SZ prefix devices where applicable.

\*\*AEC-Q release available upon request.

### MMBZHxxVAWT1G Series, SZMMBZHxxVAWT1G Series

**TYPICAL CHARACTERISTICS** 

#### 18 15 12 (V<sub>BR</sub> @ I<sub>T</sub>) 9 6 З 0 -40 0 + 50 +100 +150 TEMPERATURE (°C)

BREAKDOWN VOLTAGE (VOLTS)

Figure 1. Typical Breakdown Voltage versus Temperature (Upper curve for each voltage is bidirectional mode,

lower curve is unidirectional mode)

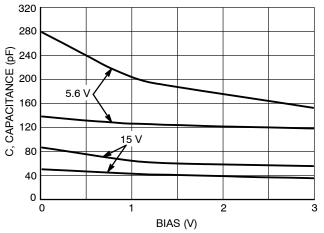


Figure 3. Typical Capacitance versus Bias Voltage (Upper curve for each voltage is unidirectional mode, lower curve is bidirectional mode)

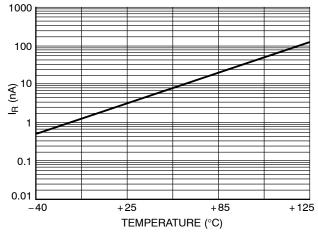


Figure 2. Typical Leakage Current versus Temperature

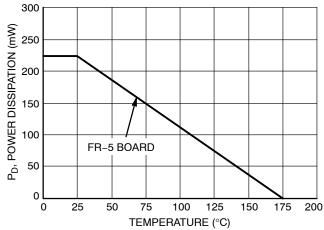


Figure 4. Steady State Power Derating Curve

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#### **TYPICAL CHARACTERISTICS**

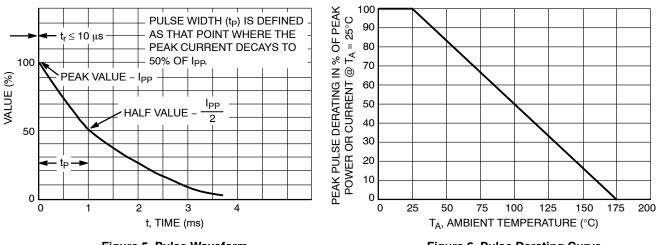
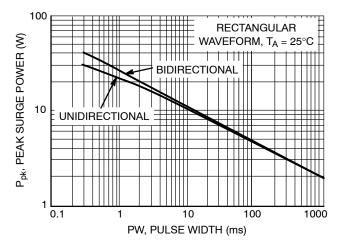


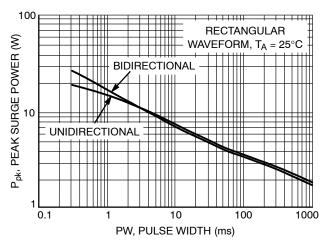
Figure 5. Pulse Waveform





#### Figure 7. Maximum Non-repetitive Surge Power, P<sub>pk</sub> versus PW

Power is defined as  $V_{RSM} \times I_Z(pk)$  where  $V_{RSM}$  is the clamping voltage at  $I_Z(pk)$ .

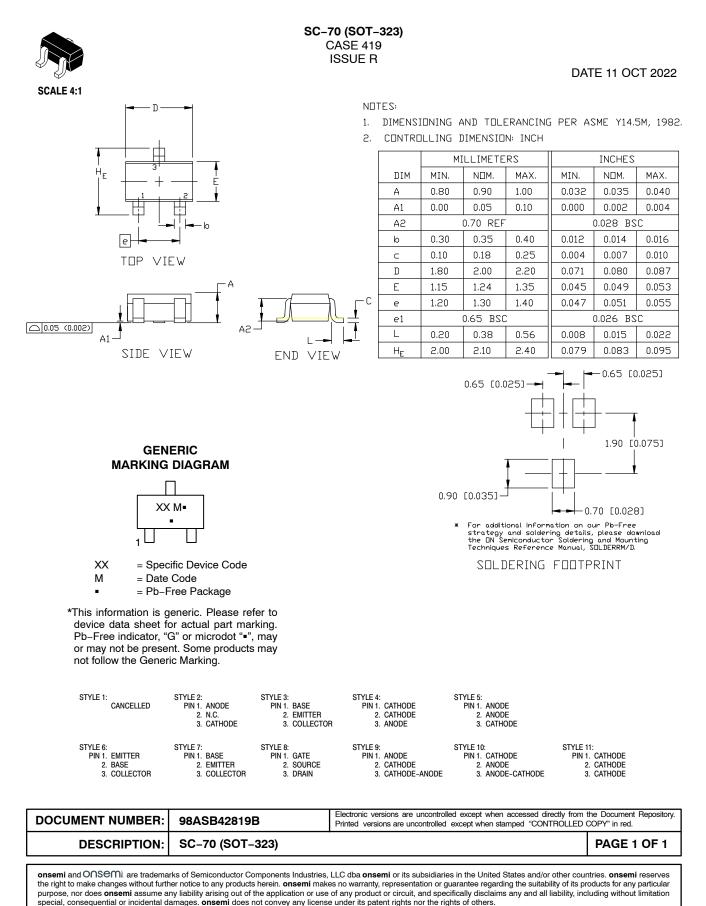


#### Figure 8. Maximum Non-repetitive Surge Power, P<sub>pk</sub>(NOM) versus PW

Power is defined as  $V_Z(NOM) \times I_Z(pk)$  where  $V_Z(NOM)$  is the nominal Zener voltage measured at the low test current used for voltage classification.

#### MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

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